

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	10/714670	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/30 11:03
L2	552	transistor with "adjacent" with capacitor	US-PGPUB	OR	ON	2006/01/30 11:04
L3	1653	transistor same "adjacent" same capacitor	US-PGPUB	OR	ON	2006/01/30 11:05
L4	163	2.clm.	US-PGPUB	OR	ON	2006/01/30 11:05
L5	8132	silicide same gate	US-PGPUB	OR	ON	2006/01/30 11:05
L6	1727	5.clm.	US-PGPUB	OR	ON	2006/01/30 11:05
L7	6	4 and 6	US-PGPUB	OR	ON	2006/01/30 11:06
L8	0	sencond same conductive with (layer film)	US-PGPUB	OR	ON	2006/01/30 11:06
L9	28701	second same conductive with (layer film)	US-PGPUB	OR	ON	2006/01/30 11:07
L10	13656	9.clm.	US-PGPUB	OR	ON	2006/01/30 11:07
L11	823778	prior before	US-PGPUB	OR	ON	2006/01/30 11:07
L12	152278	11.clm.	US-PGPUB	OR	ON	2006/01/30 11:07
L13	2	7 and 9 and 12	US-PGPUB	OR	ON	2006/01/30 11:08